L Number	Hits	Search Text	DB	Time stamp
Number	1	("6154028").PN.	USPAT; US-PGPUB	2003/07/14
-	7	Magnetoelectric near3 sensing	USPAT;	2003/07/14
-	606	Magnetoresistive near3 sensing	US-PGPUB USPAT; US-PGPUB	13:07 2003/07/14 13:29
	5	microfine near2 (wire wiring)	US-PGPUB USPAT; US-PGPUB	2003/07/14 13:08
-	468735	resin	USPAT; US-PGPUB	2003/07/14 2003:08
-	0	(Magnetoresistive near3 sensing) and (microfine near2 (wire wiring))	USPAT;	2003/07/14 13:08
	22	(Magnetoresistive near3 sensing) and	USPAT; US-PGPUB	2003/07/14
-	110	stack\$3 and Magnetoresistive near3 sensing	USPAT; US-PGPUB	2003/07/14
-	468735		USPAT; US-PGPUB	- 2003/07/14 - 13:29
-	3	(stack\$3 and Magnetoresistive near3 sensing) and resin	USPAT; US-PGPUB	0003/07/14 14:16
-	1	("5393351").PN.	USPAT; US-PGPUB	2003/07/14 14:17
-	269	(73/:04.26).ccLs.	USPAT; US-PGPUB	2003/07/14
-	564048	resin silicone siloxane polysiloxane polyorganosiloxane polydiorganosiloxane	USPAT; US-PGPUB	2003/07/14 14:48
-	52	((73/204.26).CCLS.) and (resin silicone siloxane polysiloxane polyorganosiloxane polydiorganosiloxane)	USPAT; US-PGPUB	2003/07/14
i –	3	Magnetoresistive near3 (resin silicone siloxane polysiloxane polyorganosiloxane polydiorganosiloxane)	USPAT; US-PGPUB	2003/07/14
-	5	Magnetoresistive near3 (resin silicone silomane polysilomane polyorganosilomane polydiorganosilomane)	EPO; JPO; LEPWENT	- 2003/07/14 - 15:09
-	61	Magnetoresistive and (resin silicone siloxane polysiloxane polyorganosiloxane polydroganosiloxane)	EPO; JPO; DEPWENT	2003/07/14 14:55
-	56	polydrorganosiloxane) (Magnetoresistive and (resin silicone siloxane polysiloxane polyorganosiloxane polydrorganosiloxane)) not	EPO; JPO; DERWENT	2003/07/14 15:07
	· · · ·	(Magnetoresistive near3 (resin silicone siloxane polysiloxane polyorganosiloxane polydroganosiloxane)		,
-	3	microfine adj wir\$3	EPO; JPO; DEPWENT	2003/07/14 15:07
-	ì	microfine adj wir\$3	US-PGPUB	2003/07/14 15:08
-	152	fusing adj temperature	US-PGPUB	2003/07/14 15:08
; -	1150	curing adj temperature	US-PGPUB	2003/07/14
-	3	<pre>(fusing adj temperature) and (curing adj temperature)</pre>	US-PGPUB	2003/07/14 15:08
-	1	Magnetoresistive near3 (resin silicone siloxane polysiloxane polyorganosiloxane polydiorganosiloxane)	USFAT; US-PGPUB	2003/07/14 15:44
		centrol adj circuit	USFAT; US-PGPUB	12003/07/14 116:30
· –	72	(Magnetoresistive near3 sensing) and (control adj circuit)	USFAT; US-PGPUB	2003/07/14 15:45
 - 	1	•	EPO; JPO; DEPWENT	13.43 12003/07/14 16:31
-	5468	FUKAMI-T\$.in. KAWANO-Y\$.in. TAGUCHI-M\$.in. YASUDA-N\$.in.	EPO; JPO; DEPWENT	2003/07/14
. -	795181	sensor	EPO; JPO; DERWENT	12003/07/14 16:32
-	268	(FUKAMI-T\$.in. KAWANO-Y\$.in. TAGUCHI-M\$.in. YASUDA-N\$.in.) and sensor	EPO; JPO; DERWENT	2003/07/14 16:34

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	1187698 resin	EPC; JPO; DEPWENT	2003/07/14	
-	13 ((FUKAMI-T\$.in. KAWANO-Y\$.in. TAGUCHI-M\$.in. YASUDA-N\$.in.) and sensor)		2003/07/14 16:37	1
i I	and resin	DEI WENT	13.37	
-	5443 magnetoresistive	EPO; JPO; DEFWENT	2003/07/14 16:37	
-	2 ((FUKAMI-T\$.in. KAWANO-Y\$.in. TAGUCHI-M\$.in. YASUDA-N\$.in.) and sensor)	EPO; JPO; DEPWENT	2003/07/14 16:39	
1	and magnetoresistive		, , , ,	
-	1 EP-1058324-\$.did.	EPO	2003/07/14 16:45	
! -	97596 air adj flow	EPO; JPC; DEPWENT	2003/07/14 16:46	:
	17 (FUKAMI-T\$.in. KAWANO-Y\$.in.	EPO; JPO;	2003/07/14	İ
	TAGUCHI-M\$.in. YASUDA-N\$.in.) and (air adj flow)	DEPWENT	16:46	!

L Number	Hits	Search Text	, DB	Time stamp	Ì
Number	1	2000W0-jp03077.ap,prai.	EPO; JPD; DEPWENT	. 2002/12/16 11:42	1
!	5260	FUKAMI-T\$.in. KAWANC-Y\$.in.	EPO; JPO;		!
i	1	TAGUCHI-M\$.in. YASUDA-N\$.in.	DEPWENT		1
<u>'</u> –	763371	sens∩r	EPO; JPO; LEPWENT	2002/12/16 09:18	
· -	255	(FUKAMI-T\$.in. KAWAND-Y\$.in.	EPO; JPO;		
•	7.50	TAGUCHI-M\$.in. YASUDA-N\$.in.) and sensor		09:18	
i	/158	photocur\$	EPO; JPO; IEPWENT	12002/12/16 09:18	
	j 0	((FUMAMI-T\$.in. KAWANO-Y\$.in.		2002/12/16	
1		TAGUCHI-M\$.in. YASUFA-N\$.in.) and sensor) and photocur\$	I EPWENT	09:19	
-	109071	silicone		10000/12/16	
_	S.	((FUHAMI-T\$.in. KAWANO-Y\$.in.	DERWENT EPO; JPO;	09:19 2002/12/16	
: : !		TAGUCHI-M\$.in. YASUDA-N\$.in.) and sensor; and silicone	DEPWENT		1
· -	2	Gb-2322452-\$.did.	EPO; JPO;		
-	ń	JP-12054843-\$.did.	DEPWENT DEPO; JPO;	09:32 2002/12/16	
		OF 1054645 Q. did.	DEPWENT	109:33	
· -	0	JP-100013616-\$.did.		1000/12/16	- 1
1_	! -	'JP-10013616-\$.did.	, DEPWENT - EPO; JPO;	09:33 0002/12/16	
1	, <u> </u>	or resident quarter.	DEPWENT	109:34	
	. 2	JP-60062279-\$.did.	The second secon	10000/12/16	
1		JP-61080039-\$.did.	FPO IPO	09:34 3002/12/15	
				.09:35	1
. –	1	JP-62178359-\$.did.	EPO; JPO;		1
_		JP-09078755-\$.did.	PEPWENT FPO: JPO:	09:35 2002/12/16	!
			LEFWENT	10:58	:
	ຸ 75ຄ	428/447	EPO; JPO;	2000/12/16	i
i	3567	. (428/447).CCLS.	LEFWENT USPAT;	10:59 2000/12/16	1
i			US-PGPUB	11:35	1
-	3 /9253	sensor	USPAT; US-PGPUB	√2002/12/16 - √10:59	- 1
-	71	((428/447).CCLS.) and sensor	USPAT;	12002/12/16	1
i I	1 7000		US-PGPUB	10:59	
i	/('bb*	<pre>((magnetoresistence (air adj flow) acelleration pressure (yaw adj rate) image near2 (sensor))</pre>	USPAT;	2002/12/16 11:17	
	۶	$\sim (((418/447).CCLS.))$ and sensor) and	"SPAT;	2002/10/16	
		<pre>(((magnetoresistence (air adj flow) acelleration pressure (yaw adj rate)</pre>	US-PGPUB	11:10	
1_	250040	<pre>image) near2 (sensor))) melogular add weight</pre>	יומהאיי.	0000116116	į
· =	. 202049	molecular adj weight	USPAT; US-PGPUB	2002/12/16 11:18	!
-	32	(((4.38/447).CCLS.) and sensor) and	USPAT;	2002/12/16	
· _		(molecular adj weight) magnetoresistence near2 sensor	US-PGPUB	11:10	
•		naghe Jo. esistence hearz sensor	USPAT; US-PGPUB	2002/12/16 11:17	
i -	339	magnetoresistance near2 sensor	USPAT;	2002/12/16	1
i _		(((428/447).CCLS.) and sensor) and	US-PGPUB USPAT;	11:18 2002/12/16	1
1		(magnetoresistance near2 sensor)	US-PGPUB	11:18	1
	. Ú	(molecular adj weight) and	USPAT;	2002/12/16	1
	i i	((((428/447).CCLS.) and sensor) and (magnetoresistance near2 sensor))	, US-PGFUB	11:18	!
· _	70988	(((magnetoresistence (air adj flow)	USPAT;	2002/12/16	
		acelleration pressure (yaw adj rate)	US-PGPUB	11:19	
		<pre>image: rear2 (sensor);) (magnetoresistance near2 sensor)</pre>			,
· -	0	wire near2 substract	USPAT;	2002/12/16	
i			US-PGPUB	11:19	1

· _		5562 wire near2 substrate	USPAT;	2002/12/16	•
			US-PGPUB	11:20	
1 -	1	10 wire near4 (polymer adj substrate)	USPAT;	2002/12/16	
i			US-PGPUB	11:21	
		1580 (molecular adj weight) and	USPAT;	2002/12/16	1
		((428/447).CCLS.)	US-PGPUB	11:25	1
_		32 sensor and ((molecular adj weight) and	USPAT;	2002/12/16	1
		((428/447).CCLS.))	'US-PGPUB	11:25	
; -		2 jp-10319597-\$.did.	EPO; JPO;	12002/12/16	1
1	:		DERWENT	11:43	
	***		•		